
FINGERPRINTS OF HOPPING CONDUCTIVITY IN DISORDERED CHARGE DENSITY WAVE SYSTEMS**D. Dominko¹, D. Starešinić¹, I. Jurić¹, K. Biljaković¹, M. Đekić^{1,2}, A. Salčinović Fetić^{1,2}**¹*Institut of Physics, Bijenička c. 46, Hr-10000 Zagreb, Croatia*²*Faculty of Science, Zmaja od Bosne 33-35, Sarajevo, Bosnia and Herzegovina*

Electric conductivity of charge density wave (CDW) systems exhibits rich variety of behavior; thermal activation across the gap at low fields below transition temperature T_p , collective contribution (nonlinear conductivity channel) above the threshold field (E_T) and variable range hopping (VRH) at low temperatures¹ and in granulated thin films in the whole temperature range². Particularly the origin of the hopping conductivity is still unclear.

We have investigated the influence of disorder on conductivity phenomena in CDW systems TaS₃ and blue bronze (BB: K_{0.3}MoO₃) in a wide range of temperatures and electric fields using both the DC and pulse measurements at low and high fields respectively. Disorder has been introduced in several ways: (1) synthesis of TaS₃ samples doped with Nb, (2) irradiation of nominally pure TaS₃ samples and (3) deposition of granular thin BB films by pulsed laser deposition (PLD).

Our results show that the nonlinear conductivity can be described by VRH already below 50 K in contrast to the linear channel, where it appears only below 20 K¹. Moreover, the point defects in TaS₃ introduced by doping and irradiation have no effect on VRH. Together with the dielectric data, it suggests the microscopic picture of soliton hopping in CDW at low temperatures^{3,4}. In granular thin BB films, on the other hand, the influence of grain boundaries is overwhelming even above T_p , which is in contrast to the previous experiments on thin BB films⁵. The results can be understood by applying recent theoretical results for Beloborodov's Efros-Shlovskii VRH in granular materials⁶.

[1] M. E. Itkis, F. Ya. Nad, and P. Monceau, *J. Phys. Cond. Matt.* 2 (1990) 8327

[2] M. Đekić et al, *Vacuum* 98 (2013) 93-99

[3] W. F. Pasveer, P. A. Bobbert, and M. A. J. Michels, *Phys. Rev. B* 74 (2006) 165209

[4] A. S. Rodin and M. M. Fogler, *Phys. Rev. B* 80 (2009) 155435

[5] O. C. Mantel, C. A. W. Bal, C. Langezaal, C. Dekker and H. S. J. Van Der Zant, *J. App. Phys.* 86, 4440 (1999)

[6] I. Beloborodov, A. Lopatin, V. Vinokur, and K. B. Efetov, *Rev. Mod. Phys.* 79 (2007) 469-518